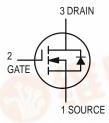
TMOS Switching

N-Channel — Enhancement



MPF960 MPF990

MAXIMUM RATINGS

dfrexs2.com

Rating	Symbol	MPF930	MPF960	MPF990	Unit
Drain-Source Voltage	V _{DS}	35	60	90	Vdc
Drain-Gate Voltage	V _{DG}	35 60 90			Vdc
Gate–Source Voltage — Continuous — Non–repetitive (t _p ≤ 50 μs)	V _G S V _{GSM}	±20 ±40			Vdc Vpk
Drain Current Continuous(1) Pulsed(2)	I _D	2.0 3.0			Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0		Watts mW/°C	
Operating and Storage Junction Temperature Range	Т _Ј , Т _{stg}	-55 to 150		°C	
Thermal Resistance	θЈА	125			°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteris	stic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	- 557	172				
Drain–Source Breakdown Voltage (VGS = 0, I _D = 10 μAdc)	MPF930 MPF960 MPF990	V _{(BR)DSX}	35 60 90		_ _ _	Vdc
Gate Reverse Current (VGS = 15 Vdc, VD	S = 0)	IGSS	_	_	50	nAdc
ON CHARACTERISTICS(2)					T. W	1
Zero-Gate-Voltage Drain Current (VDS = Maximum Rating, VGS = 0)		IDSS	- 4	3-7-7	10	μAdo
Gate Threshold Voltage (ID = 1.0 mAdc, VDS = VGS)		V _{GS(Th)}	1.0	NAI'P	3.5	Vdc
Orain-Source On-Voltage (V _{GS} = 10 Vdc) (I _D = 0.5 Adc)	MPF930 MPF960 MPF990	V _{DS(on)}	_ _ _	0.4 0.6 0.6	0.7 0.8 1.2	Vdc
(I _D = 1.0 Adc)	MPF930 MPF960 MPF990		_ _ _	0.9 1.2 1.2	1.4 1.7 2.4	
(I _D = 2.0 Adc)	MPF930 MPF960 MPF990		_ _ _	2.2 2.8 2.8	3.0 3.5 4.8	

The Power Dissipation of the package may result in a lower continuous drain current.
 Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.



MPF930 MPF960 MPF990

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS(2) (Continued)						
Static Drain–Source On Resistance (V _{GS} = 10 Vdc, I _D = 1.0 Adc)	MPF930 MPF960 MPF990	^r DS(on)	_ _ _	0.9 1.2 1.2	1.4 1.7 2.0	Ω
On-State Drain Current (VDS = 25 Vdc, VGS = 10 Vdc)		I _{D(on)}	1.0	2.0	_	Amps
SMALL-SIGNAL CHARACTERISTICS		•				•
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{iss}	_	70	_	pF
Reverse Transfer Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{rss}	_	20	_	pF
Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{oss}	_	49	_	pF
Forward Transconductance (V _{DS} = 25 Vdc, I _D = 0.5 Adc)		9fs	200	380	_	mmhos
SWITCHING CHARACTERISTICS						•
Turn-On Time		ton	_	7.0	15	ns
Turn-Off Time		toff	_	7.0	15	ns

^{2.} Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

RESISTIVE SWITCHING

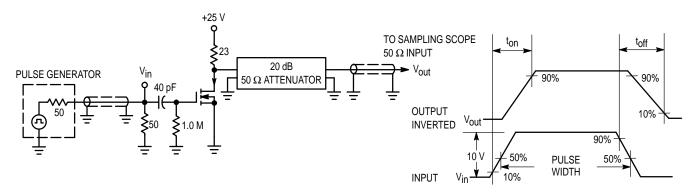


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

MPF930 MPF960 MPF990

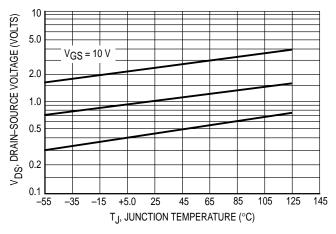


Figure 3. On Voltage versus Temperature

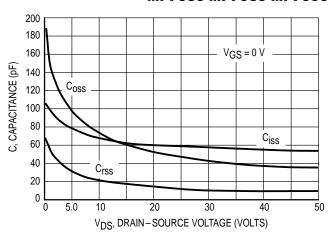


Figure 4. Capacitance Variation

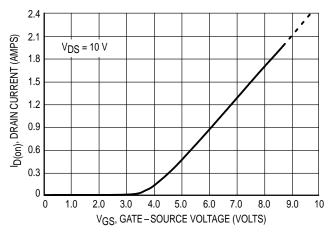


Figure 5. Transfer Characteristic

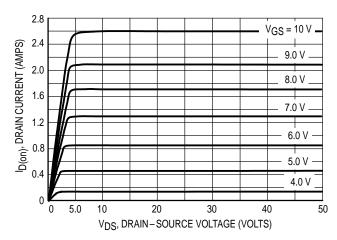


Figure 6. Output Characteristic

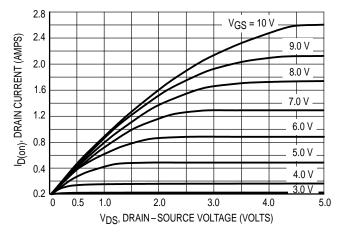
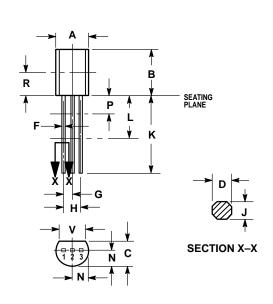


Figure 7. Saturation Characteristic

PACKAGE DIMENSIONS



CASE 029-05 (TO-226AE) ISSUE AD

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.175	0.205	4.44	5.21		
В	0.290	0.310	7.37	7.87		
С	0.125	0.165	3.18	4.19		
D	0.018	0.022	0.46	0.56		
F	0.016	0.019	0.41	0.48		
G	0.045	0.055	1.15	1.39		
Н	0.095	0.105	2.42	2.66		
J	0.018	0.024	0.46	0.61		
K	0.500		12.70	_		
L	0.250		6.35			
N	0.080	0.105	2.04	2.66		
Р		0.100		2.54		
R	0.135		3.43			
٧	0.135		3.43			

STYLE 22:

PIN 1. SOURCE

GATE

DRAIN

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